μPA2460T1Q

MOS FIELD EFFECT TRANSISTOR

R07DS0185EJ0100
Rev.1.00
Dec 06, 2010

Description

The μPA2460T1Q is a switching device, which can be driven directly by a 2.5 V power source.

The μPA2460T1Q features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

Features

- 2.5 V drive available
- Low on-state resistance
  - $R_{DS(on)1}$ = 17.5 mΩ MAX. (V_{GS} = 4.5 V, I_D = 3.0 A)
  - $R_{DS(on)2}$ = 18.5 mΩ MAX. (V_{GS} = 4.0 V, I_D = 3.0 A)
  - $R_{DS(on)3}$ = 22.0 mΩ MAX. (V_{GS} = 3.1 V, I_D = 3.0 A)
  - $R_{DS(on)4}$ = 27.5 mΩ MAX. (V_{GS} = 2.5 V, I_D = 3.0 A)
- Built-in G-S protection diode against ESD

Ordering Information

Part No.	LEAD PLATING	PACKING	Package
μPA2460T1Q-E1-AX *1	Ni/Pd/Au	8 mm embossed taping 3000 p/reel	8-pin HUSON (2720)

Note: *1. Pb-free (This product does not contain Pb in the external electrode and other parts.)

Absolute Maximum Ratings (T_A = 25°C)

Item	Symbol	N-CHANNEL	Unit
Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	20	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	±12	V
Drain Current (DC) *1	$I_{D(DC)}$	±6.5	A
Drain Current (pulse) *2	$I_{D(pulse)}$	±60	A
Total Power Dissipation (2 unit) *1	P_{T1}	1.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	−55 to +150	°C

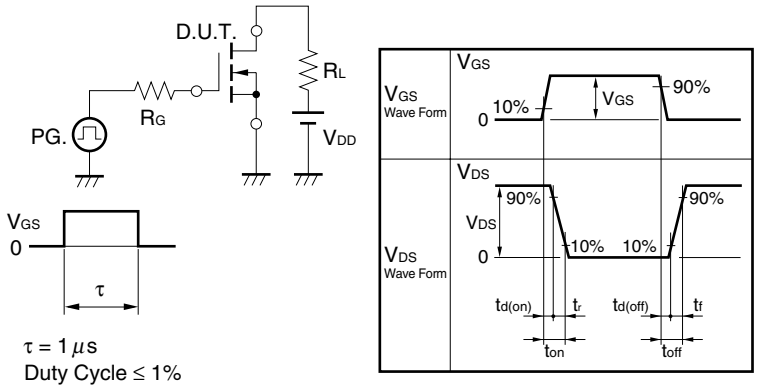
Notes: *1. Mounted on a glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mmt
*2. PW ≤ 10 μs, Duty Cycle ≤ 1%

Electrical Characteristics (T_A = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	I_{DSS}			1	μA	V_{DS} = 20 V, V_{GS} = 0 V
Gate Leakage Current	I_{GSS}			±10	μA	V_{GS} = ±12 V, V_{DS} = 0 V
Gate to Source Cut-off Voltage	$V_{GS(off)}$	0.5	1.0	1.5	V	V_{DS} = 10 V, I_D = 1 mA
Forward Transfer Admittance *1	$\|y_{fs}\|$	2.5			S	V_{DS} = 10 V, I_D = 3.0 A
Drain to Source On-state Resistance *1	$R_{DS(on)1}$	11	14.5	17.5	mΩ	V_{GS} = 4.5 V, I_D = 3.0 A
	$R_{DS(on)2}$	11.5	15	18.5	mΩ	V_{GS} = 4.0 V, I_D = 3.0 A
	$R_{DS(on)3}$	12	16.5	22	mΩ	V_{GS} = 3.1 V, I_D = 3.0 A
	$R_{DS(on)4}$	15.3	19	27.5	mΩ	V_{GS} = 2.5 V, I_D = 3.0 A
Input Capacitance	C_{iss}		810		pF	V_{DS} = 10 V,
Output Capacitance	C_{oss}		110		pF	V_{GS} = 0 V,
Reverse Transfer Capacitance	C_{rss}		85		pF	f = 1 MHz
Turn-on Delay Time	$t_{d(on)}$		3		μs	V_{DD} = 10 V, I_D = 3.0 A,
Rise Time	t_r		6		μs	V_{GS} = 4 V,
Turn-off Delay Time	$t_{d(off)}$		15		μs	R_G = 6 Ω
Fall Time	t_f		11		μs	
Total Gate Charge	Q_G		8		nC	V_{DD} = 16 V,
Gate to Source Charge	Q_{GS}		1.5		nC	V_{GS} = 4 V,
Gate to Drain Charge	Q_{GD}		3		nC	I_D = 6.5 A
Body Diode Forward Voltage *1	$V_{F(S-D)}$		0.83		V	I_F = 6.5 A, V_{GS} = 0 V

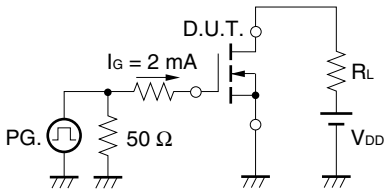
Note: *1. Pulsed

TEST CIRCUIT 1 SWITCHING TIME



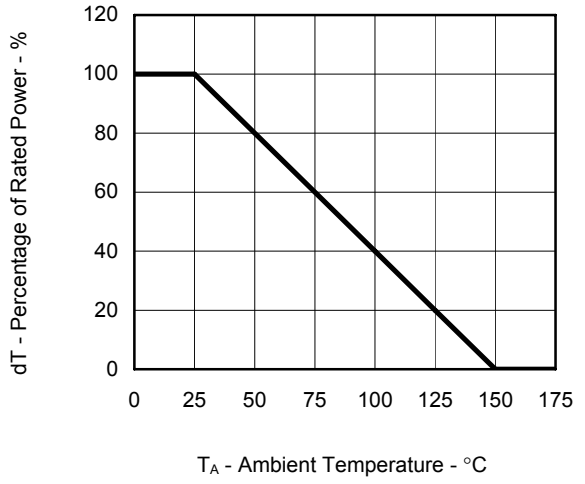
τ = 1 μs
Duty Cycle ≤ 1%

TEST CIRCUIT 2 GATE CHARGE

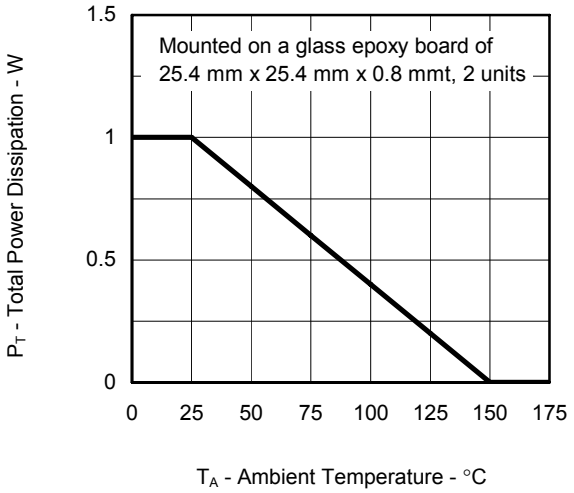


Typical Characteristics (T_A = 25°C)

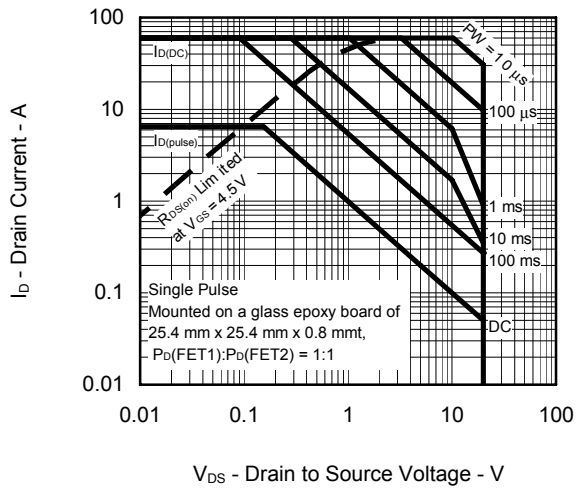
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



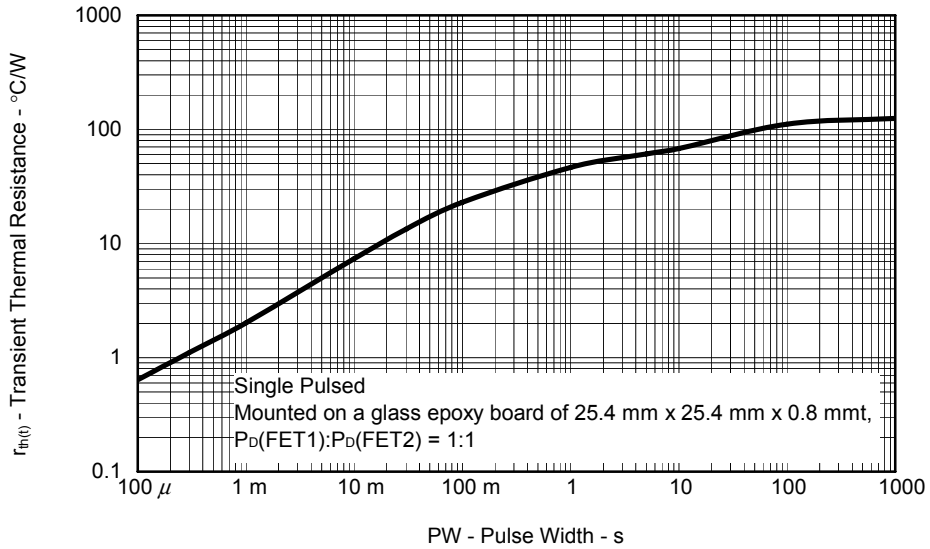
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



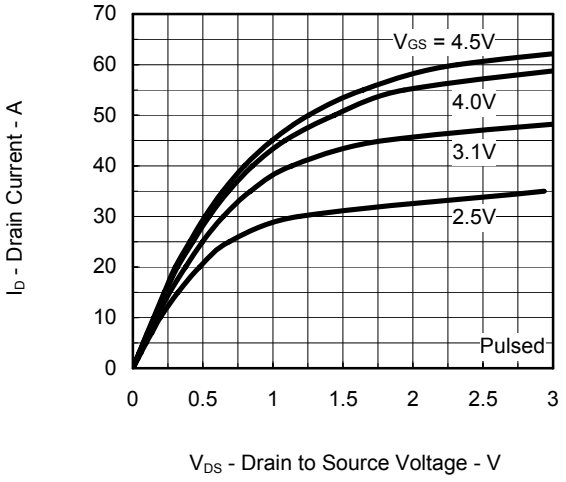
FORWARD BIAS SAFE OPERATING AREA



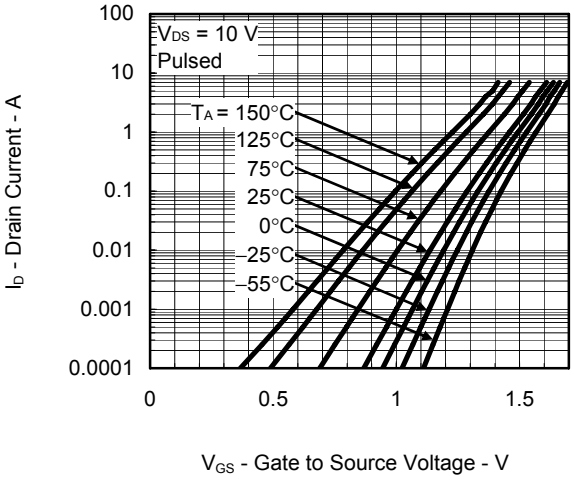
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



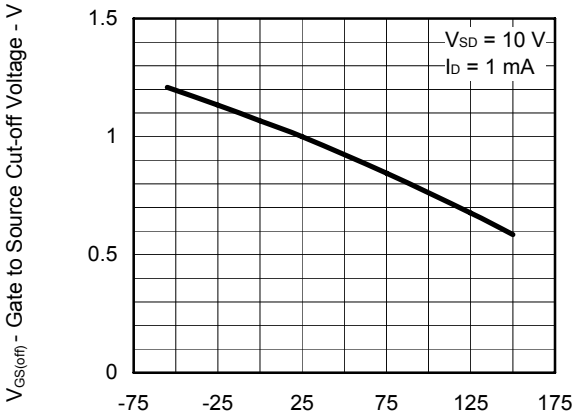
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



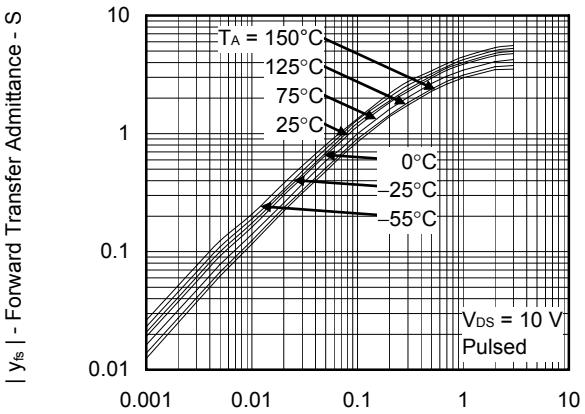
FORWARD TRANSFER CHARACTERISTICS



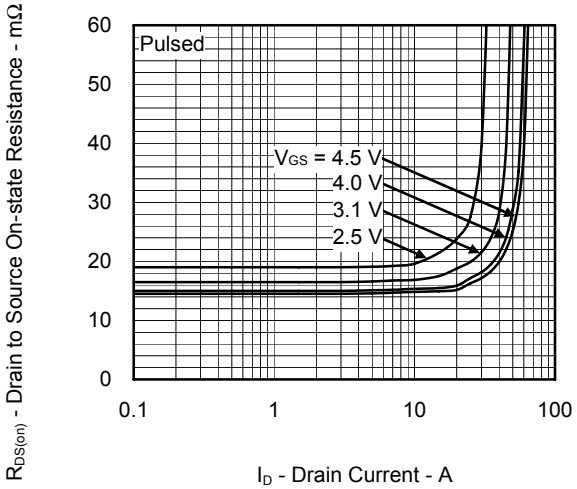
GATE TO SOURCE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



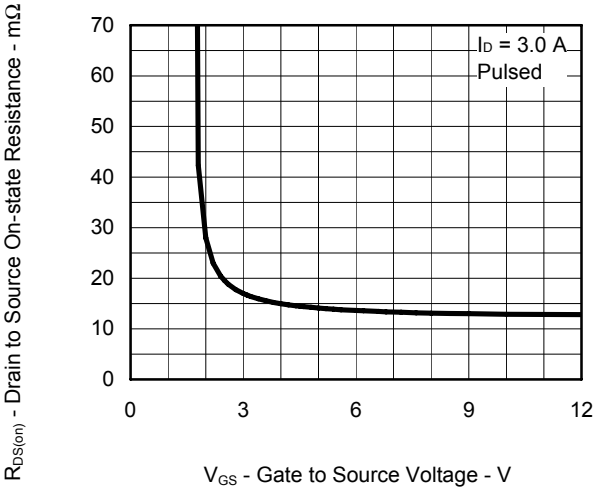
FORWARD TRANSFER ADMITTANCE vs. DRAIN
CURRENT



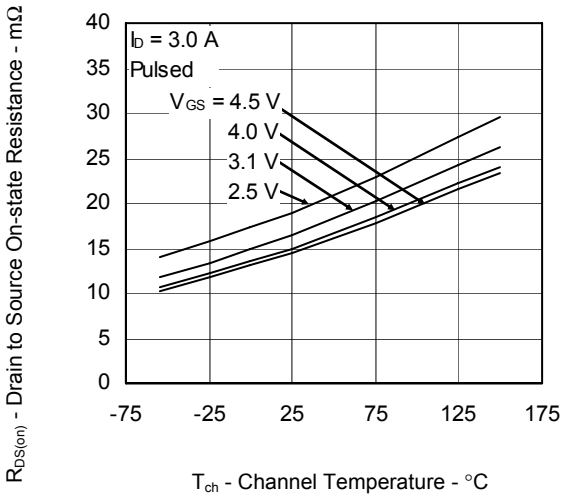
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



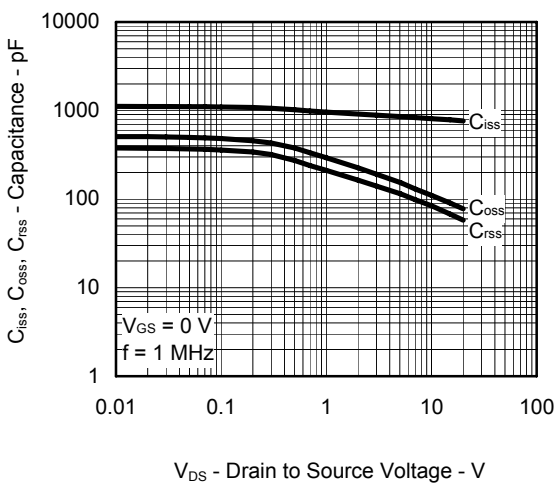
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



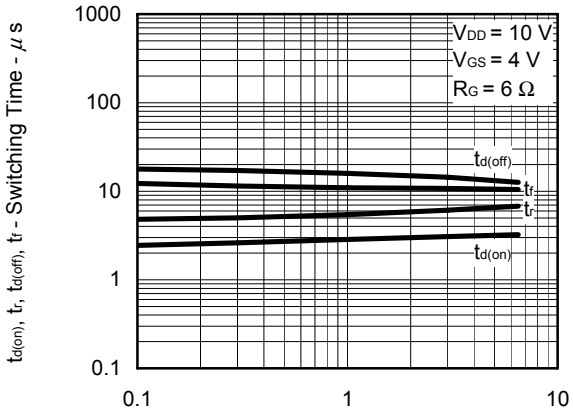
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



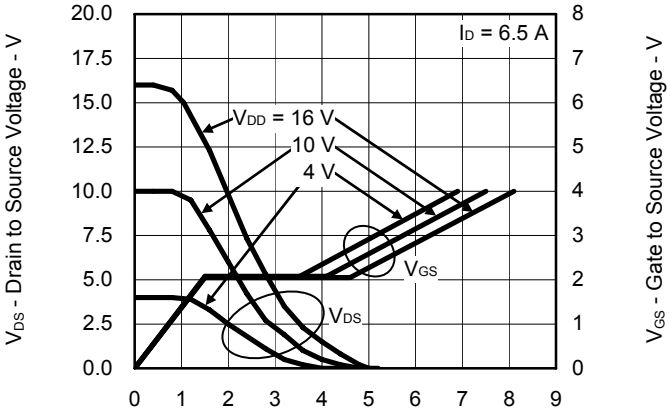
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



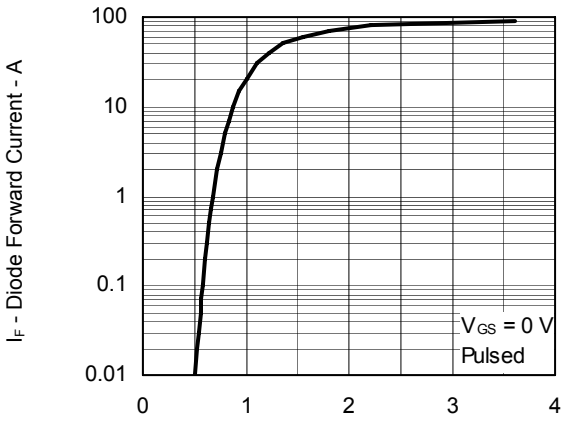
SWITCHING CHARACTERISTICS



DYNAMIC INPUT/OUTPUT CHARACTERISTICS

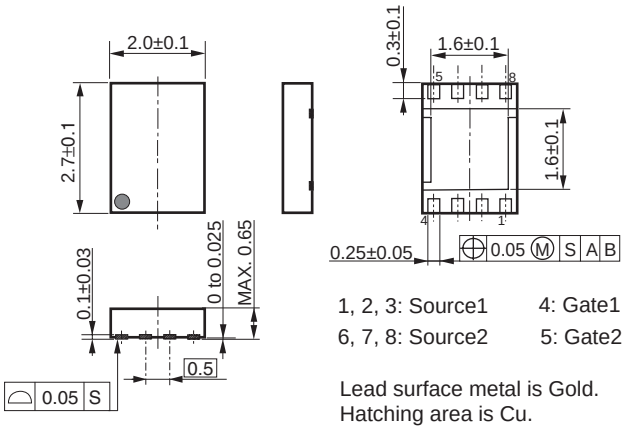


SOURCE TO DRAIN DIODE FORWARD VOLTAGE

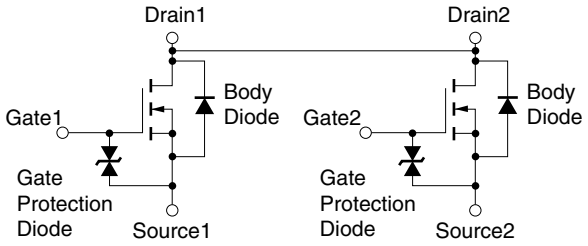


Package Drawings (Unit: mm)

8-pin HUSON (2720)



Equivalent Circuit



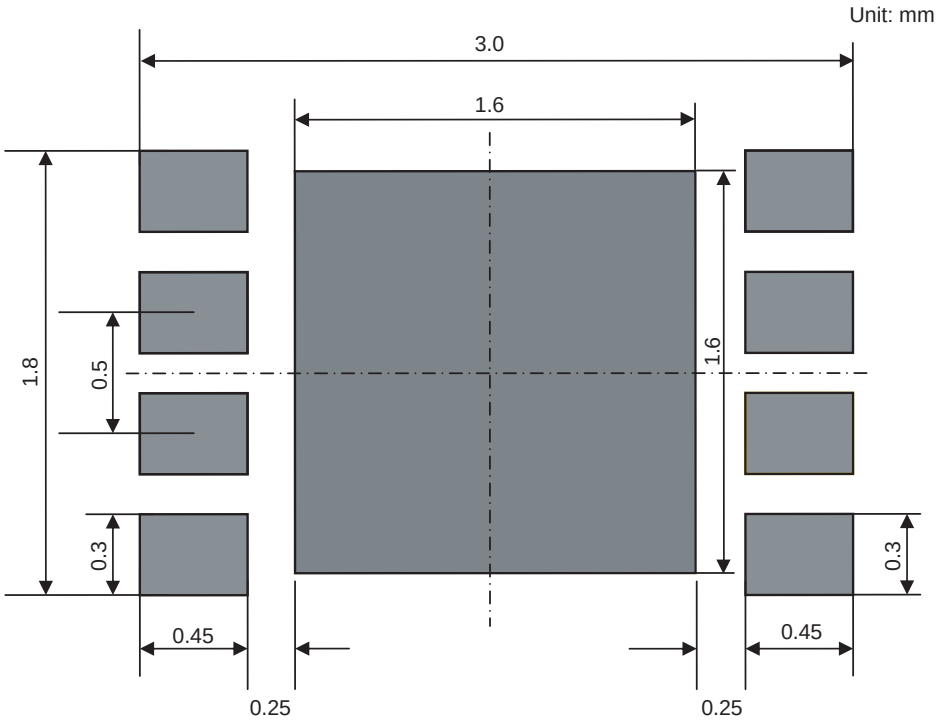
Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

<Notes for using this device safely>

When you use this device, in order to prevent a customer's hazard and damage, use it with understanding the following contents. If used exceeding recommended conditions, there is a possibility of causing failure of the device and characteristic degradation.

1. When you mount the device on a substrate, carry out within our recommended soldering conditions of infrared reflow. If mounted exceeding the conditions, the characteristic of a device may be degraded and it may result in failure.
2. When you wash the device mounted the substrate, carry out within our recommended conditions. If washed exceeding the conditions, the characteristic of a device may be degraded and it may result in failure.
3. When you use ultrasonic wave to substrate after the device mounting, prevent from touching a resonance generator directly. If it touches, the characteristic of a device may be degraded and it may result in failure.
4. Please refer to **Figure 1** as an example of the land pattern. Optimize the land pattern in consideration of density, appearance of solder fillets, common difference, etc in an actual design.

Figure 1. Example of the land pattern



Revision History	μPA2460T1Q Data Sheet

Rev.	Date	Description	
		Page	Summary
1.00	Dec 06, 2010	–	First Edition Issued

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